

3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O, BUS-HOLD

## **FEATURES:**

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4μ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Supports hot insertion
- · Available in 96-ball LFBGA package

#### **DRIVE FEATURES:**

- Balanced Output Drivers: ±24mA
- · Reduced system switching noise

# **APPLICATIONS:**

- · 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

## **DESCRIPTION:**

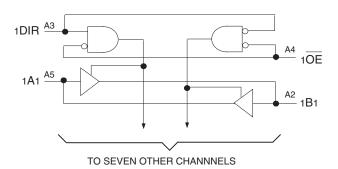
This 32-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate the device as either four independent 8-bit transceivers or one 32-bit transceiver. The direction control pins (DIR) control the direction of data flow. The output enable pins (OE) override the direction control and disable both ports. All inputs are designed with hysteresis for improved noise margin.

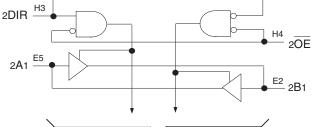
All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

The LVCH32245A has been designed with a  $\pm 24$ mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance

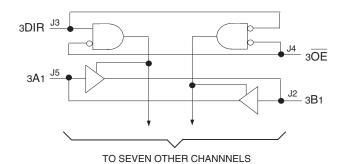
The LVCH32245A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

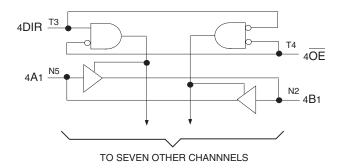
# **FUNCTIONAL BLOCK DIAGRAM**





TO SEVEN OTHER CHANNNELS





# **INDUSTRIAL TEMPERATURE RANGE**

# **PIN CONFIGURATION**

								I								
6	1 <b>A</b> 2	1 <b>A</b> 4	1 <b>A</b> 6	1 <b>A</b> 8	2 <b>A</b> 2	2 <b>A</b> 4	2 <b>A</b> 6	2 <b>A</b> 7	3 <b>A</b> 2	3 <b>A</b> 4	3 <b>A</b> 6	3 <b>A</b> 8	4 <b>A</b> 2	4 <b>A</b> 4	4 <b>A</b> 6	4 <b>A</b> 7
5	1 <b>A</b> 1	1 <b>A</b> 3	1 <b>A</b> 5	1 <b>A</b> 7	2 <b>A</b> 1	2 <b>A</b> 3	2 <b>A</b> 5	2 <b>A</b> 8	3 <b>A</b> 1	3 <b>A</b> 3	3 <b>A</b> 5	3 <b>A</b> 7	4 <b>A</b> 1	4 <b>A</b> 3	4 <b>A</b> 5	4 <b>A</b> 8
4	1OE	GND	Vcc	GND	GND	Vcc	GND	2ŌĒ	зŌЕ	GND	Vcc	GND	GND	Vcc	GND	4ŌĒ
3	1DIR	GND	Vcc	GND	GND	Vcc	GND	2DIR	3DIR	GND	Vcc	GND	GND	Vcc	GND	4DIR
2	1B1	1B3	1 <b>B</b> 5	1B7	2B1	2B3	2 <b>B</b> 5	2B8	3B1	3B3	3B5	3B7	4B1	4B3	4 <b>B</b> 5	4B8
1	1B2	1B4	1B6	1B8	2B2	2B4	2B6	2B7	3B2	3B4	3B6	3B8	4B2	4B4	4B6	4B7
	Α	В	С	D	Е	F	G	Н	J	K	L	М	N	Р	R	Т

LFBGA TOPVIEW

# 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

# ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-50 to +50	mA
lık lok	Continuous Clamp Current, VI < 0 or Vo < 0	<b>–</b> 50	mA
Icc Iss	Continuous Current through each Vcc or GND	±100	mA

#### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **CAPACITANCE** (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	рF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

#### NOTE:

1. As applicable to the device type.

# **PIN DESCRIPTION**

Pin Names	Description			
xŌĒ	Output Enable Input (Active LOW)			
xDIR	Direction Control Input			
xAx	Side A Inputs or 3-State Outputs <sup>(1)</sup>			
хВх	Side B Inputs or 3-State Outputs <sup>(1)</sup>			

#### NOTE

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

# **FUNCTION TABLE(1)**

Inp	outs	
xŌĒ	xDIR	Outputs
L	L	Bus B data to Bus A
L	Н	Bus A data to Bus B
Н	Х	Z

#### NOTE:

- 1. H = HIGH Voltage Level
  - L = LOW Voltage Level
  - X = Don't Care
  - Z = High Impedance

# **BUS-HOLD CHARACTERISTICS**

Symbol	Parameter <sup>(1)</sup>	Test Conditions		Min.	Typ. <sup>(2)</sup>	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	Vı = 2V	-75	_	_	μA
IBHL			Vı = 0.8V	75	_	_	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	Vı = 1.7V		_	_	μΑ
IBHL			Vı = 0.7V	_	_	_	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	Vı = 0 to 3.6V	_	_	±500	μΑ
IBHLO							

#### NOTES:

- 1. Pins with Bus-Hold are identified in the pin description.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Con	ditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
ViH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		l –	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
lін	Input Leakage Current	Vcc = 3.6V	Vı = 0 to 5.5V	-	_	±5	μΑ
lıL							
lozh	High Impedance Output Current	Vcc = 3.6V Vo = 0 to 5.5V		-	_	±10	μΑ
lozL	(3-State Output pins)						
loff	Input/Output Power Off Leakage	Vcc = 0V, Vin or Vo ≤ 5.5V		l –	_	±50	μΑ
Vık	Clamp Diode Voltage	Vcc = 2.3V, lin = -18mA		_	-0.7	-1.2	V
VH	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		<u> </u>	_	10	μΑ
ICCH ICCZ		$3.6 \le \text{Vin} \le 5.5 \text{V}^{(2)}$		<del> </del>	_	10	
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other in	_	_	500	μΑ	

## NOTES:

- 1. Typical values are at Vcc = 3.3V, +25°C ambient.
- 2. This applies in the disabled state only.

# **OUTPUT DRIVE CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Max.	Unit
Voн	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = — 6mA	2	_	
		Vcc = 2.3V	Iон = - 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V		2.4	_	
		Vcc = 3V	Iон = - 24mA	2.2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 6mA	_	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IoL = 24mA	_	0.55	

#### NOTE:

<sup>1.</sup> VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = -40°C to +85°C.

# **OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, Ta = 25°C**

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	76	pF
CPD	Power Dissipation Capacitance per Transceiver Outputs disabled		8	

# **SWITCHING CHARACTERISTICS**(1)

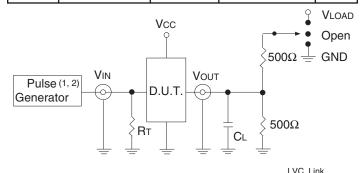
		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
<b>t</b> PLH	Propagation Delay	1.5	4.7	1	4	ns
tPHL	xAx to xBx, xBx to xAx					
tpzh	Output Enable Time	1.5	6.7	1.5	5.5	ns
tpzl	xOE to xAx or xBx					
tpHZ	Output Disable Time	1.5	7.1	1.5	6.6	ns
tPLZ	xOE to xAx or xBx					
tpzh	Output Enable Time	1.5	7	1.5	5.5	ns
tpzl	xDIR to xAx or xBx					
tpHZ	Output Disable Time	1.5	7.4	1.5	6.6	ns
tPLZ	xDIR to xAx or xBx					
tsk(o)	Output Skew <sup>(2)</sup>	_	_	_	500	ps

#### NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA = -40°C to + 85°C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

# TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc <sup>(1)</sup> =3.3V±0.3V	Vcc <sup>(1)</sup> =2.7V	Vcc <sup>(2)</sup> =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
ViH	2.7	2.7	Vcc	٧
VT	1.5	1.5	Vcc/2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

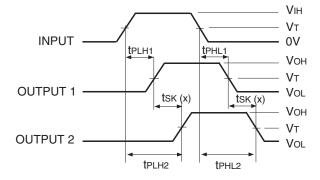
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

# NOTES:

- 1. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

## **SWITCH POSITION**

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

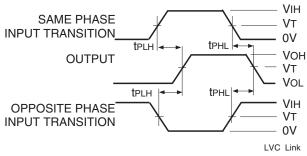


tsk(x) = |tplh2 - tplh1| of tphl2 - tphl1

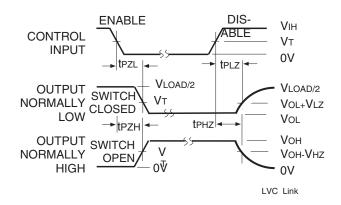
Output Skew - tsk(x)

#### NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



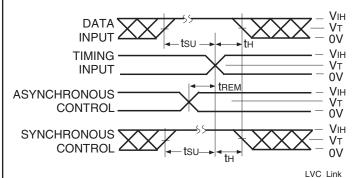
# Propagation Delay



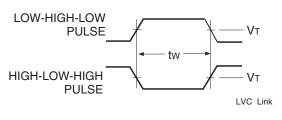
#### Enable and Disable Times

#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

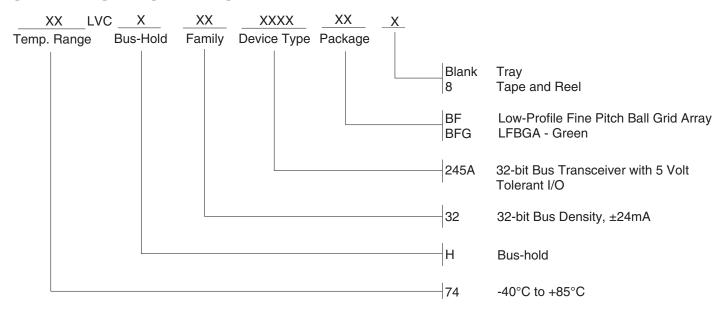


Set-up, Hold, and Release Times



Pulse Width

# ORDERING INFORMATION



# **Orderable Part Information**

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
Α	74LVCH32245ABF	BF96	CABGA	I
	74LVCH32245ABF8	BF96	CABGA	I
	74LVCH32245ABFG	BFG96	CABGA	ı
	74LVCH32245ABFG8	BFG96	CABGA	I

# **Datasheet Document History**

02/29/2016 Pg. 7 Updated the ordering information by adding Tape and Reel.

04/01/2021 Pg. 1-7 Rebranded as a Renesas datasheet. Added new table of orderable part information.

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